

**In the Claims:**

Please amend claims 1, 6, 7, 12 and 14 as follows:

1. (Amended) A display system comprising:

a plurality of semiconductor light-emitting devices embedded in an insulation layer, each of said semiconductor light-emitting devices having a lower end surface disposed on a substrate, an exposed upper end portion and a light-emitting region provided between said lower end surface and said upper end portion; and

a conductor film provided on an upper surface of said insulation layer and in contact with an upper end portion electrode on said exposed upper end portions of said semiconductor light-emitting devices;

wherein said light-emitting region is at a slant angle relative to said lower end surface.

6. (Amended) A display system as set forth in claim 1, wherein each said semiconductor light-emitting device has a primary light-emitting direction in the direction from said light-emitting region toward a lower end surface on said substrate surface, and said light-emitting region includes at least one reflective surface for directing light in said primary light-emitting direction.

7. (Amended) A display system as set forth in claim 6, wherein each said semiconductor light-emitting device is formed in a pyramid shape or a truncated pyramid shape, and having at least one slant surface as said reflective surface.

12. (Amended) A display system as set forth in claim 1, wherein each said semiconductor light-emitting device comprises a first conduction type semiconductor layer, an active layer and a second conduction type semiconductor layer sequentially laminated, said insulation layer is thinned, and said conductor film is formed on a surface formed by said second conduction type semiconductor layer exposed by said thinning said insulation layer, whereby said upper end portion electrode and said conductor film are formed as one body with each other.

14. (Amended) A display system as set forth in claim 1, wherein each said semiconductor light-emitting device comprises a first conduction type semiconductor layer, an active layer and a second conduction type semiconductor layer sequentially laminated, a contact metal layer of a predetermined thickness is formed on said second conduction type semiconductor layer, said insulation layer is thinned, and said conductor film is formed on a surface formed by said contact metal layer exposed by said thinning said insulation layer, whereby said upper end portion electrode and said conductor film are formed as one body with each other.